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Thieno[3,4-d][1,3]dithiole-2-thione

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Key indicators: single-crystal X-ray study; T = 294 K; mean σ (C–C) = 0.002 Å; R factor = 0.021; wR factor = 0.053; data-to-parameter ratio = 17.8.

In the title compound, $C_5H_2S_4$, the terminal monocyclic S atom deviates by 0.117 (1) Å from the mean plane of the other non-H atoms (r.m.s. deviation = 0.001 Å). All six C–S bonds and the central C–C bond in the rings are characterized by π -conjugated lengths, endowing the molecule with high π -conjugation. In the crystal, the molecules are parallel packed, forming columnar stacks along the *a* axis. Short intermolecular S···S contacts [3.397 (1) and 3.486 (1) Å], are observed.

Related literature

For details of the synthesis, see: Chiang *et al.* (1983); Gronowitz & Moses (1962). For DFT calculations using *GAUSSIAN*, see: Frisch *et al.* (2003).



Experimental

Crystal data C₅H₂S₄

 $M_r = 190.31$

Orthorhombic, $P2_12_12_1$ a = 3.9425 (1) Å b = 9.2588 (2) Å c = 19.2368 (3) Å V = 702.20 (3) Å³

Data collection

Bruker APEX2 CCD area-detector diffractometer Absorption correction: multi-scan (SADABS; Bruker, 2005) $T_{min} = 0.792, T_{max} = 0.962$

Refinement

$$\begin{split} R[F^2 > 2\sigma(F^2)] &= 0.021\\ wR(F^2) &= 0.053\\ S &= 1.05\\ 1601 \text{ reflections}\\ 90 \text{ parameters}\\ \text{All H-atom parameters refined} \end{split}$$

Z = 4Mo K\alpha radiation $\mu = 1.25 \text{ mm}^{-1}$ T = 294 K $0.20 \times 0.06 \times 0.03 \text{ mm}$

17824 measured reflections 1601 independent reflections 1486 reflections with $I > 2\sigma(I)$ $R_{\text{int}} = 0.030$

 $\begin{array}{l} \Delta \rho_{\rm max} = 0.25 \ {\rm e} \ {\rm \AA}^{-3} \\ \Delta \rho_{\rm min} = -0.13 \ {\rm e} \ {\rm \AA}^{-3} \\ {\rm Absolute \ structure: \ Flack \ (1983),} \\ 618 \ {\rm Friedel \ pairs} \\ {\rm Flack \ parameter: \ 0.18 \ (10)} \end{array}$

Data collection: *APEX2* (Bruker, 2005); cell refinement: *SAINT* (Bruker, 2005); data reduction: *SAINT*; program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *SHELXTL* (Sheldrick, 2008); software used to prepare material for publication: *SHELXL97*.

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: BG2422).

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S1. Comment

Although the synthesis of the title compound was reported early by Gronowitz & Moses, 1962, there is no report about its crystal structure. We have recently re-synthesized this compound and determined its X-ray structure.

The molecule adopts a nearly planar C_{2v} conformation (see below for details). All the C—S bond lengths, from the longest 1.744 (2)Å to the shortest 1.635 (2) Å, are between the lengths of C—S single bond and C=S double bond. The central C=C bond, shared by the two fused five-member rings, also features a delocalized bond with its length being 1.430 (2) Å. Thus the molecule is characterized by a highly planar π -conjugation.

The molecules pack in a paralleled way along the *a* axis, forming columnar stacks along this direction. The molecular packing is also characterized by many short intermolecular S…S contacts (for instance, S2…S2 [-1/2 + x, 1/2 - y, -z] and S3…S4 [1 - x, -1/2 + y, 1/2 - z] distances are 3.397 (1)Å and 3.486 (1) Å, respectively). We believe that this kind of S…S intermolecular interactions helps to stabilitate the molecular packing in the crystal.

The terminal S4 atom deviates by 0.117 (1)Å from the least-squares plane through the other eight non-H atoms (C1, C2, C3, C4, C5, S1, S2, S3). We suppose that this deviation may be the result of the above S…S intermolecular interactions. To support this assumption, we carried out an optimization procedure for the molecular conformation by using the Gaussian-03 programs (Frisch *et al.*, 2003) within the framework of the DFT at the B3LYP/6–311(*d*) level. The optimized "free" molecule indeed adopts a perfect planar conformation with a strict C_{2v} symmetry. All the theoretical bond parameters are in good agreement with those of the X-ray results.

S2. Experimental

The title compound was synthesized by a similar procedure to Chiang *et al.* (1983). 3,4-Dibromothiophene (2.18 g, 9.0 mmol) was dissolved in 30 ml anhydrous diethyl ether and stirred in the presence of N_2 at 195 K while *n*-butyllithium (5.6 ml, 9.0 mmol, 1.6 *M* in hexane) was added *via* syringe. Stirring was continued for 0.5 h, then sulfur (0.288 g, 9.0 mmol) was added. The reaction mixture was stirred for 1 h, and *n*-butyllithium (5.6 ml, 9.0 mmol) was added *via* syringe. After being stirred for 0.5 h, sulfur (0.288 g, 9.0 mmol) was added to the yellow solution. After 1 h, the reaction mixture was allowed to come to r.t. and was dried *in vacuo*. After removal of the solvent, 2 *M* sodium hydroxide solution (20 ml) and carbon disulfide (12 ml) were added. The mixture was refluxed under N_2 at 363 K for 4 h. And then the solution was stirred overnight at r.t.. The excess of carbon disulfide was removed *in vacuo*. Filtration of the mixture gave a yellow solid. Recrytallization of the solid from dichloromethane-hexane (1:5, *v/v*) gave 0.26 g (15% yield) of the compound. Crystals were grown by slow evaporation of a dichloromethane solution.

S3. Refinement

Both H atoms were located in a difference Fourier map and freely refined in isotropic approximation, leading to C—H distances 0.88 (2), 0.94 (2) Å and Uiso 0.045 (5), 0.060 (7)Å⁻¹.



Figure 1

Molecular structure of the title compound. Displacement elliposoid is drawn at 50% probability level.



Figure 2

The packing of the molecules in title crystal viewed down the a axis, showing the column structure along this direction and S…S intermolecular short contacts between neighboring columns.

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Crystal data	
$C_5H_2S_4$	<i>a</i> = 3.9425 (1) Å
$M_r = 190.31$	b = 9.2588 (2) Å
Orthorhombic, $P2_12_12_1$	c = 19.2368 (3) Å
Hall symbol: P 2ac 2ab	V = 702.20 (3) Å ³

Z = 4 F(000) = 384 $D_x = 1.800 \text{ Mg m}^{-3}$ Mo K\alpha radiation, $\lambda = 0.71073 \text{ Å}$ Cell parameters from 6079 reflections

Data collection

Bruker APEX2 CCD area-detector diffractometer Radiation source: fine-focus sealed tube Graphite monochromator Detector resolution: 8.3 pixels mm⁻¹ phi and ω scans Absorption correction: multi-scan (*SADABS*; Bruker, 2005) $T_{\min} = 0.792, T_{\max} = 0.962$

Refinement

Refinement on F^2 Least-squares matrix: full $R[F^2 > 2\sigma(F^2)] = 0.021$ $wR(F^2) = 0.053$ S = 1.051601 reflections 90 parameters 0 restraints Primary atom site location: structure-invariant direct methods $\theta = 2.4-26.6^{\circ}$ $\mu = 1.25 \text{ mm}^{-1}$ T = 294 KBar, yellow $0.20 \times 0.06 \times 0.03 \text{ mm}$

17824 measured reflections 1601 independent reflections 1486 reflections with $I > 2\sigma(I)$ $R_{int} = 0.030$ $\theta_{max} = 27.5^{\circ}, \ \theta_{min} = 2.4^{\circ}$ $h = -5 \rightarrow 5$ $k = -12 \rightarrow 12$ $l = -24 \rightarrow 25$

Secondary atom site location: difference Fourier map Hydrogen site location: difference Fourier map All H-atom parameters refined $w = 1/[\sigma^2(F_o^2) + (0.0337P)^2 + 0.0176P]$ where $P = (F_o^2 + 2F_c^2)/3$ $(\Delta/\sigma)_{max} < 0.001$ $\Delta\rho_{max} = 0.25$ e Å⁻³ $\Delta\rho_{min} = -0.13$ e Å⁻³ Absolute structure: Flack (1983), **618 Friedel pairs** Absolute structure parameter: 0.18 (10)

Special details

Experimental. Scan width $0.5^{\circ} \omega$, Crystal to detector distance 5.96 cm **Geometry**. All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted *R*-factor *wR* and goodness of fit *S* are based on F^2 , conventional *R*-factors *R* are based on *F*, with *F* set to zero for negative F^2 . The threshold expression of $F^2 > \sigma(F^2)$ is used only for calculating *R*-factors(gt) *etc.* and is not relevant to the choice of reflections for refinement. *R*-factors based on F^2 are statistically about twice as large as those based on *F*, and *R*- factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters $(Å^2)$

	x	у	Ζ	$U_{ m iso}$ */ $U_{ m eq}$	
S1	0.00458 (13)	-0.19316 (5)	0.07833 (3)	0.04533 (13)	
S2	-0.01295 (11)	0.26695 (5)	0.07145 (2)	0.03376 (11)	
S3	0.28209 (12)	0.16829 (5)	0.20312 (2)	0.03822 (12)	
S4	0.25260 (16)	0.48015 (5)	0.17223 (3)	0.05033 (14)	
C1	-0.0743 (5)	-0.0312 (2)	0.03940 (10)	0.0403 (4)	
C2	0.0144 (4)	0.08048 (18)	0.08177 (8)	0.0306 (3)	

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C3	0.1522 (4)	0.03202 (19)	0.14643 (9)	0.0321 (3)
C4	0.1774 (4)	0.31270 (18)	0.15017 (8)	0.0313 (4)
C5	0.1610 (5)	-0.1139 (2)	0.15177 (11)	0.0415 (4)
H1	-0.168 (5)	-0.030 (2)	-0.0057 (13)	0.060 (7)*
H2	0.230 (5)	-0.162 (2)	0.1886 (10)	0.045 (5)*

Atomic displacement parameters (\mathring{A}^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
S 1	0.0560 (3)	0.0293 (2)	0.0507 (3)	0.0022 (2)	-0.0044 (3)	-0.00404 (19)
S2	0.0428 (2)	0.0297 (2)	0.0288 (2)	0.0009 (2)	-0.00395 (19)	0.00159 (16)
S3	0.0476 (2)	0.0372 (2)	0.0299 (2)	0.0011 (2)	-0.00840 (19)	0.00048 (17)
S4	0.0692 (3)	0.0328 (2)	0.0490 (3)	-0.0045 (3)	-0.0055 (3)	-0.0084 (2)
C1	0.0485 (11)	0.0348 (9)	0.0377 (10)	0.0017 (9)	-0.0078 (8)	-0.0023 (8)
C2	0.0331 (8)	0.0292 (8)	0.0296 (8)	0.0024 (7)	0.0005 (8)	0.0003 (6)
C3	0.0336 (8)	0.0323 (9)	0.0303 (8)	0.0014 (7)	0.0015 (6)	0.0023 (7)
C4	0.0323 (8)	0.0327 (9)	0.0289 (8)	-0.0002 (7)	0.0016 (6)	-0.0017 (7)
C5	0.0527 (11)	0.0326 (10)	0.0391 (10)	0.0054 (8)	-0.0018 (8)	0.0027 (8)

Geometric parameters (Å, °)

S1—C1	1.705 (2)	S4—C4	1.6345 (17)
S1—C5	1.707 (2)	C2—C1	1.362 (2)
S2—C2	1.7412 (17)	C2—C3	1.429 (2)
S2—C4	1.7422 (17)	C3—C5	1.355 (2)
S3—C4	1.7308 (17)	С5—Н2	0.879 (19)
S3—C3	1.7445 (18)	C1—H1	0.94 (2)
C1—S1—C5	92.94 (9)	C3—C5—S1	110.88 (15)
C2—S2—C4	96.62 (8)	C3—C5—H2	125.0 (13)
C4—S3—C3	96.94 (8)	S1—C5—H2	124.0 (12)
C1—C2—C3	112.34 (16)	C2C1S1	110.97 (14)
C1—C2—S2	131.94 (14)	C2—C1—H1	129.9 (14)
C3—C2—S2	115.72 (12)	S1—C1—H1	119.2 (14)
C5—C3—C2	112.87 (17)	S4—C4—S3	122.45 (10)
C5—C3—S3	131.76 (15)	S4—C4—S2	122.31 (10)
C2—C3—S3	115.37 (13)	S3—C4—S2	115.24 (9)
C4—S2—C2—C1	-177.48 (19)	S3—C3—C5—S1	-178.73 (11)
C4—S2—C2—C3	3.09 (15)	C1—S1—C5—C3	0.08 (16)
C1—C2—C3—C5	-0.7 (2)	C3—C2—C1—S1	0.7 (2)
S2—C2—C3—C5	178.87 (14)	S2—C2—C1—S1	-178.73 (12)
C1—C2—C3—S3	178.54 (13)	C5—S1—C1—C2	-0.46 (16)
S2—C2—C3—S3	-1.92 (18)	C3—S3—C4—S4	-177.35 (11)
C4—S3—C3—C5	178.7 (2)	C3—S3—C4—S2	2.45 (10)
C4—S3—C3—C2	-0.32 (14)	C2—S2—C4—S4	176.50 (11)
C2—C3—C5—S1	0.3 (2)	C2—S2—C4—S3	-3.29 (11)